BAND SWITCHING DIODE

Features

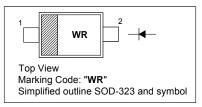
- · Small surface mounted type
- High reliability

Applications

· High frequency switching

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Absolute Maximum Ratings (T_a = 25 °C)

Parameter	Symbol	Value	Unit
Reverse Voltage	V _R	35	V
Forward Current	Io	100	mA
Junction Temperature	T _J	125	°C
Storage Temperature Range	T _{stg}	- 55 to + 125	°C

Electrical Characteristics at $T_a = 25$ °C

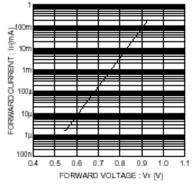
			I
Parameter	Symbol	Max.	Unit
Forward Voltage at I _F = 10 mA	V _F	1	V
Reverse Current at V _R = 25 V	I _R	10	nA
Capacitance between Terminals at $V_R = 6 \text{ V}$, $f = 1 \text{ MHz}$	C _T	1.2	pF
Forward Operating Resistance at I_F = 2 mA, f = 100 MHz	r _F	0.9	Ω







SEMTECH ELECTRONICS LTD.



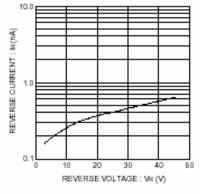


Fig. 1 Forward characteristics

Fig. 2 Reverse characteristics

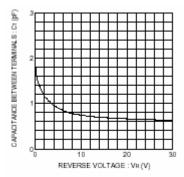


Fig. 3 Capacitance between terminals characteristics

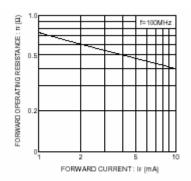


Fig. 4 Forward operating resistance characteristics









PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323

